

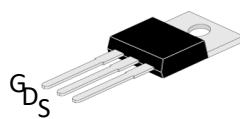


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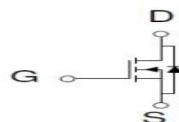
N-CHANNEL POWER MOSFET



TO-220C



TO-252 (D-PAK)



CD58N06 (TO-220C)

CDD58N06 (TO-252)

TO-220C, TO-252(D-PAK)

Plastic Package

RoHS compliant

FEATURES:

1. $V_{DS}=60V$, $I_D=58A$
2. $R_{DS(ON)} = 10m\Omega$ (Typ.) @ $V_{GS} = 10V$
3. Low Gate Charge
4. Low Reverse Recovery Voltage
5. Fast Switching
6. Improved dv/dt Capability

APPLICATION:

1. UPS
2. DC_DC Power Converters
3. Synchronous Rectification

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

Parameters	Symbol	TO220C	TO-252	Unit
Drain-Source Voltage	V_{DS}	60		V
Gate-Source Voltage	V_{GS}	± 20		V
Continuous Drain Current ($T_c = 25^\circ C$)	I_D	58		A
Continuous Drain Current ($T_c = 100^\circ C$)		40		
Pulsed Drain Current *	I_{DM}	200		A
Power Dissipation ($25^\circ C$)	P_D	85		W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.56		$^\circ C/W$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	60	$^\circ C/W$
Operating and Storage Temperature Range	T_j, T_{STG}	-50 to +150		$^\circ C$



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ELECTRICAL CHARACTERISTICS (at $T_a = 25^\circ\text{C}$ Unless otherwise specified)

Off Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_D=250\mu\text{A}$	60	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=60\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate to Body Leakage Current	I_{GSS}	$V_{\text{DS}}=0\text{V}, V_{\text{GS}}=\pm 20\text{V}$	-	-	± 100	nA

On Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Gate Threshold Voltage	$V_{\text{GS}(\text{TH})}$	$V_{\text{DS}}=V_{\text{GS}}, I_D= 250\mu\text{A}$	1.2	-	2.5	V
Static Drain-Source on-Resistance	$R_{\text{DS}(\text{on})}^{**}$	$V_{\text{GS}}=10\text{V}, I_D=30\text{ A}$	-	10	13	$\text{m}\Omega$
	$R_{\text{DS}(\text{on})}^{**}$	$V_{\text{GS}}=4.5\text{V}, I_D=30\text{A}$	-	12	15	

Dynamic Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitance	C_{iss}	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f = 1.0\text{MHz}$	-	2127	-	pF
Output Capacitance	C_{oss}		-	225	-	pF
Reverse Transfer Capacitance	C_{rss}		-	168	-	pF
Total Gate Charge	Q_g	$V_{\text{DS}}=48\text{V}, I_D=3\text{ A}, V_{\text{GS}}=10\text{V}$	-	50	-	nC
Gate-Source Charge	Q_{gs}		-	10	-	nC
Gate-Drain("Miller") Charge	Q_{gd}		-	14	-	nC

Switching Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=30\text{V}, I_D=30\text{A}, R_G=24\Omega, V_{\text{GS}}=10\text{ V}$	-	14	-	ns
Turn-on Rise Time	t_r		-	58	-	ns
Turn-off Delay Time	$t_{\text{d}(\text{off})}$		-	160	-	ns
Turn-off Fall Time	t_f		-	104	-	ns

Drain-Source Diode Characteristics and Maximum Ratings

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Maximum Continuous Drain to Source Diode Current	I_s		-	-	58	A
Maximum Pulsed Drain to Source Diode Forward	I_{sp}		-	-	232	A
Drain to Source Diode Forward	V_{SD}	$V_{\text{GS}}=0\text{V}, I_s=58\text{A}$	-	-	1.4	V
Reverse Recovery Time	t_{rr}	$V_{\text{GS}}=0\text{V}, I_s=58\text{A},$	-	22	-	ns
	Q_{rr}		-	20	-	nC

Notes:

* Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

** Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Performance Characteristics

Fig 1. Gate charge circuit and waveform

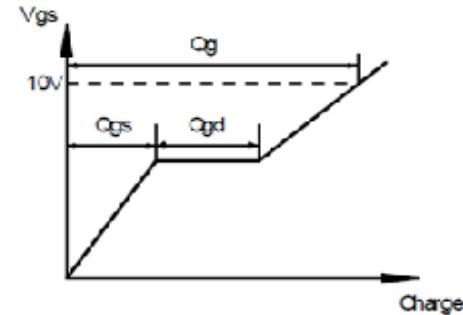
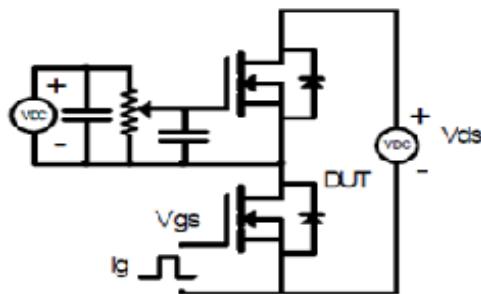


Fig 2. Switch time circuit and waveform

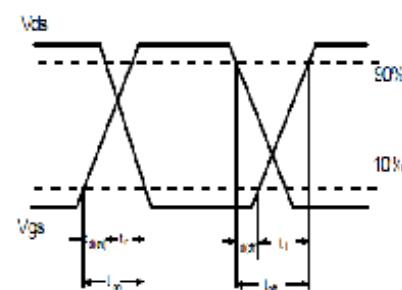
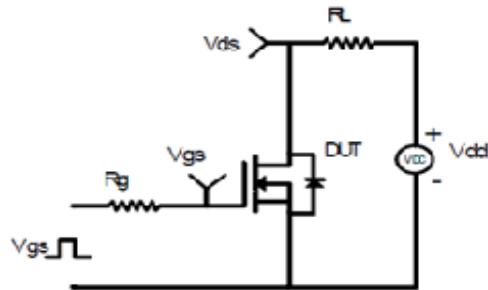


Fig 3. Reverse recovery test circuit and waveform

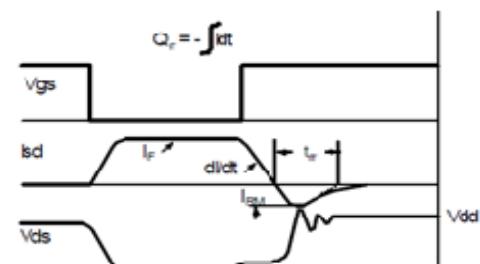
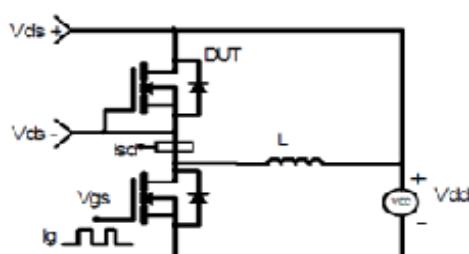
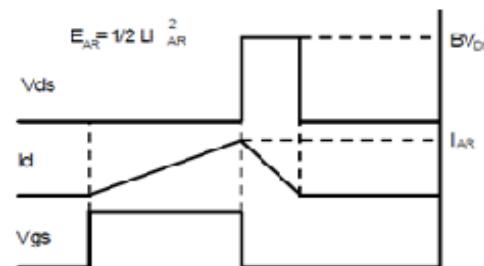
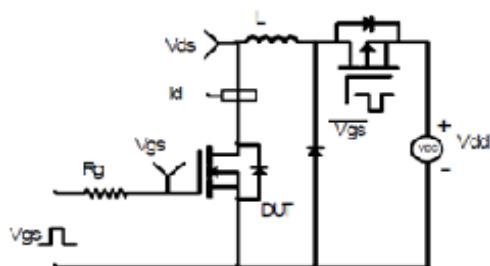


Fig 4. EAS test circuit and waveform



Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.

Figure 1

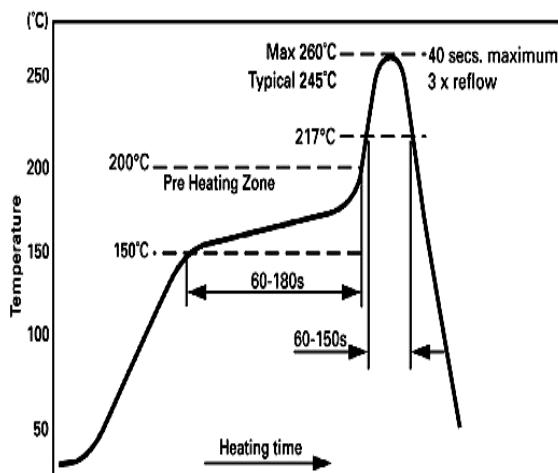
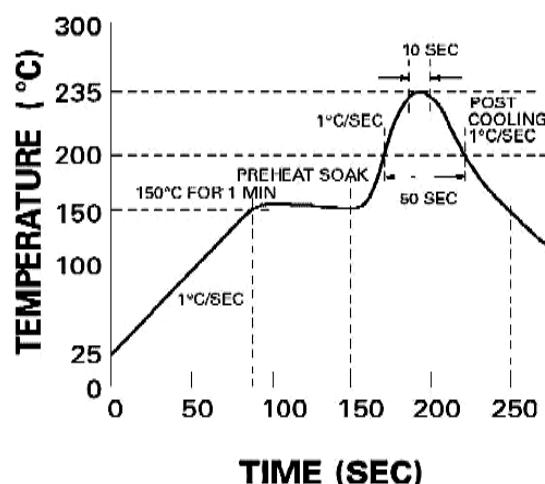


Figure 2



Reflow profiles in tabular form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~3°C/second	~3°C/second
Preheat		
– Temperature Range	150-170°C	150-200°C
– Time	60-180 seconds	60-180 seconds
Time maintained above:		
– Temperature	200°C	217°C
– Time	30-50 seconds	60-150 seconds
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	40 seconds
Ramp-Down Rate	3°C/second max.	6°C/second max.



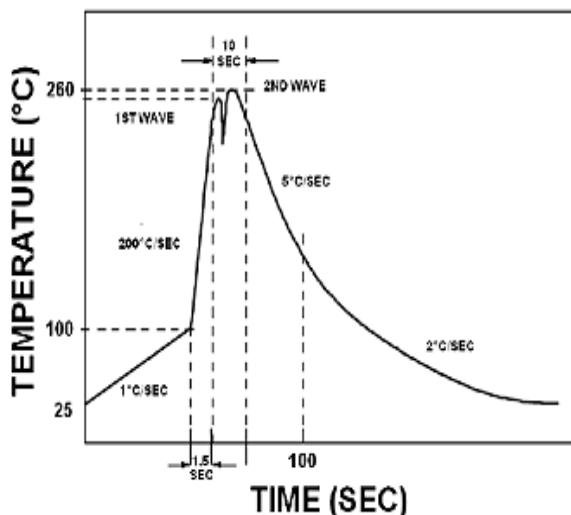
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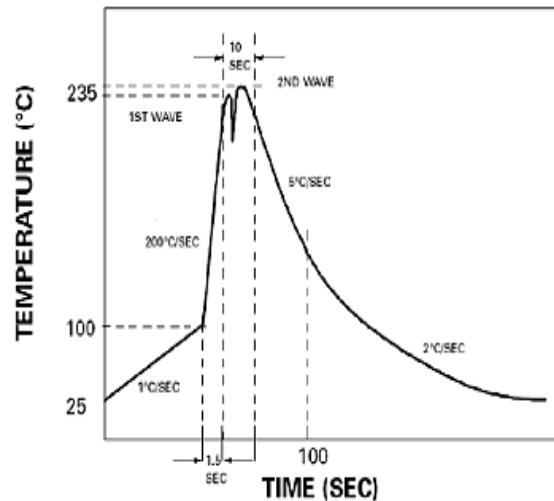


Recommended Wave Solder Profiles

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used



The Recommended solder Profile For Devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with leaded solder



Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System
Average Ramp-Up Rate	~200°C/second	~200°C/second
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp
Peak Temperature	235°C	260°C max.
Time within +0 -5°C of actual Peak	10 seconds	10 seconds
Ramp-Down Rate	5°C/second max.	5°C/second max

Typical Characteristics Curves

Fig 5: Typical Output Characteristics

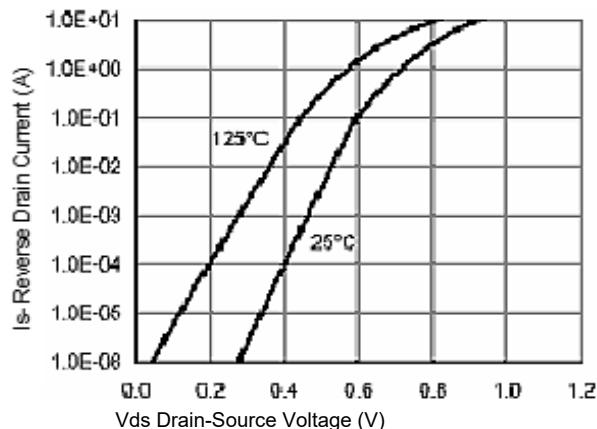


Fig 7: Body-Diode Characteristics

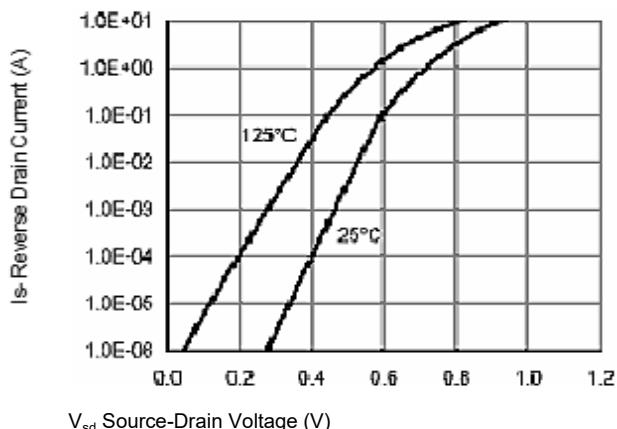


Fig 9: Capacitance Characteristics

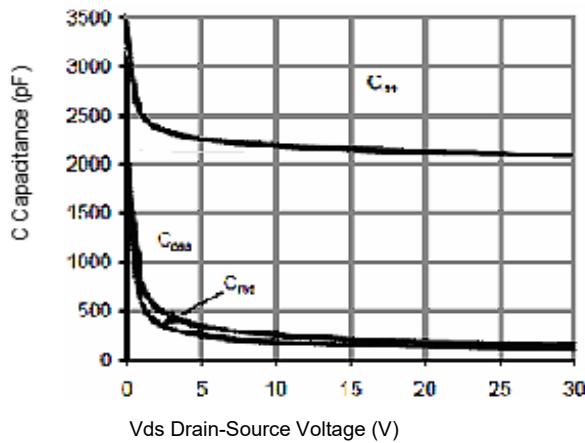


Fig 6: Typical Transfer Characteristics

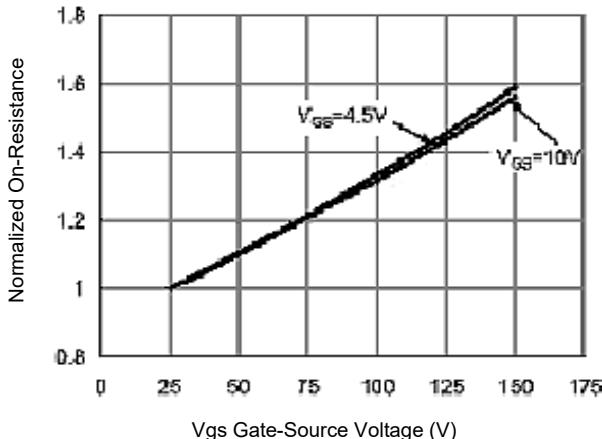


Fig 8. On-Resistance vs.JunctionTemperature

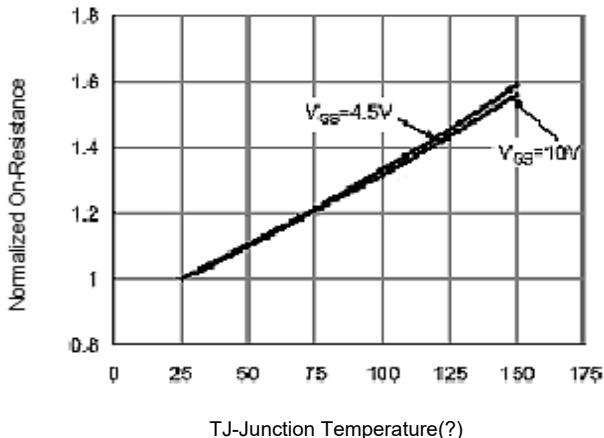
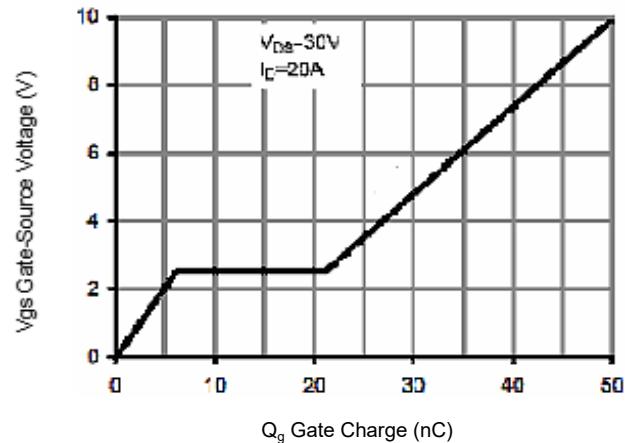


Fig 10: Gate-Charge Characteristics



Typical Characteristics Curves

Fig 11. Maximum Forward Biased Safe Operating Area

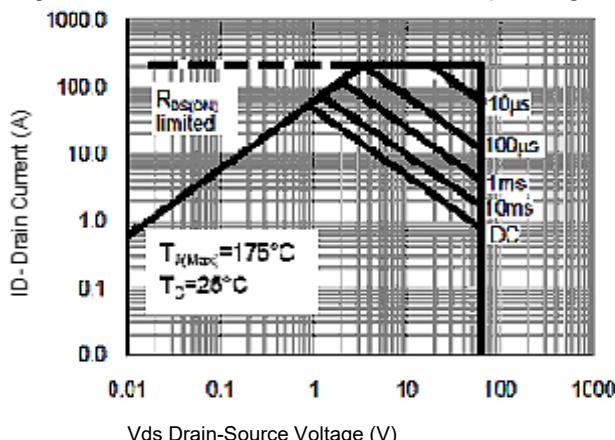


Fig 12: Current De-rating

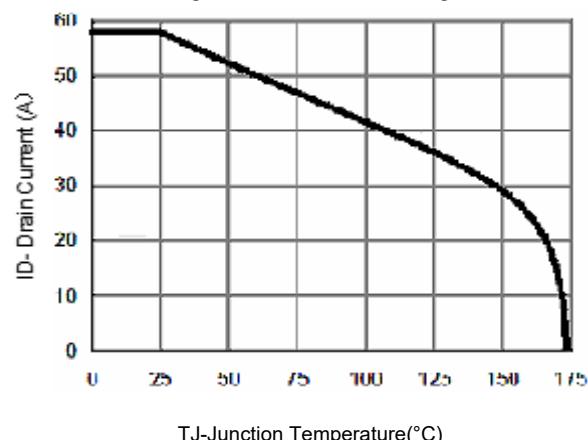


Fig 13: Power De-rating

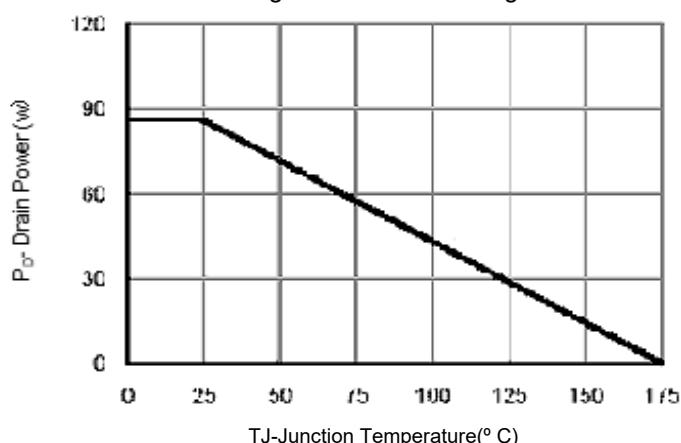
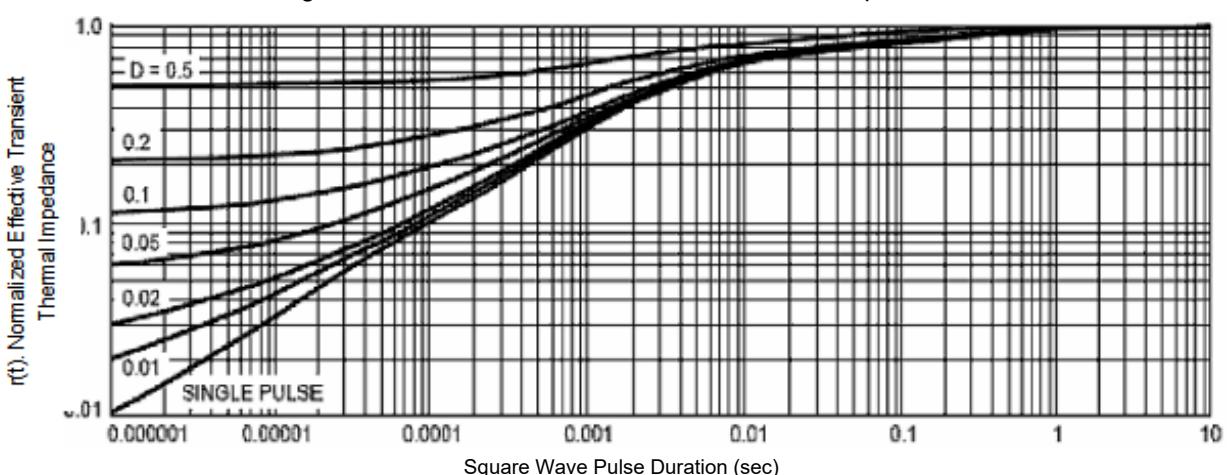


Fig 14: Normalized Maximum Transient Thermal Impedance





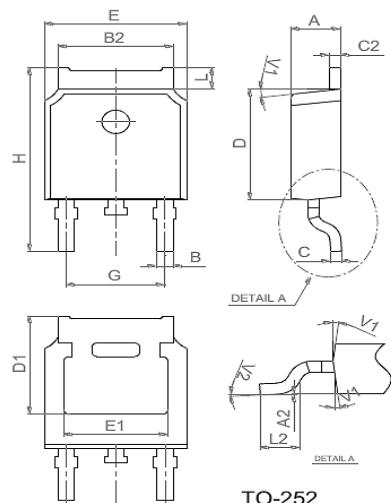
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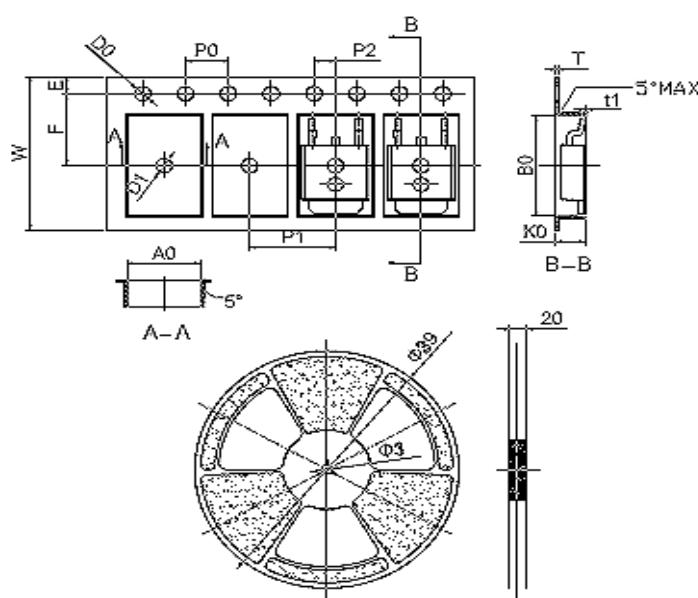
Package Details

Package: TO-252 (D-PAK) Surface mount Plastic Package



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1°		7°			7°	
V2°	0		0.6°	0		0.6°

Reel Specification-TO-252 (D-PAK)



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583

Packing	Reels (Pcs)	Per Carton (Pcs)	Tape& Reel
Taping	2,500	25,000	13 inch

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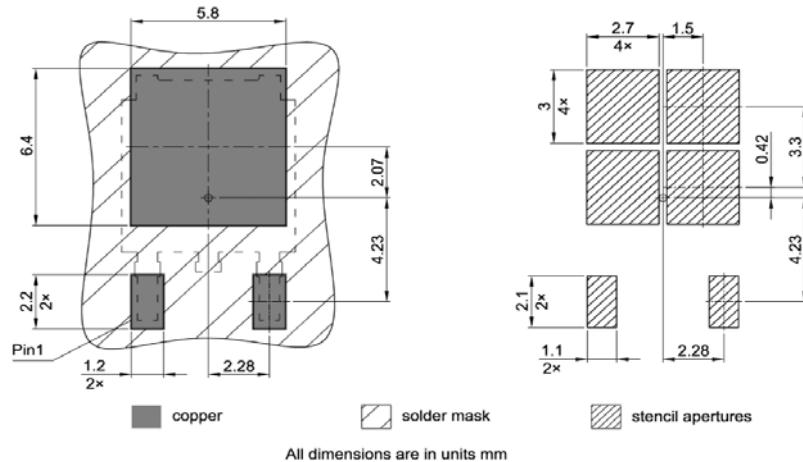


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Recommended Soldering pads for TO-252 (D-PAK)





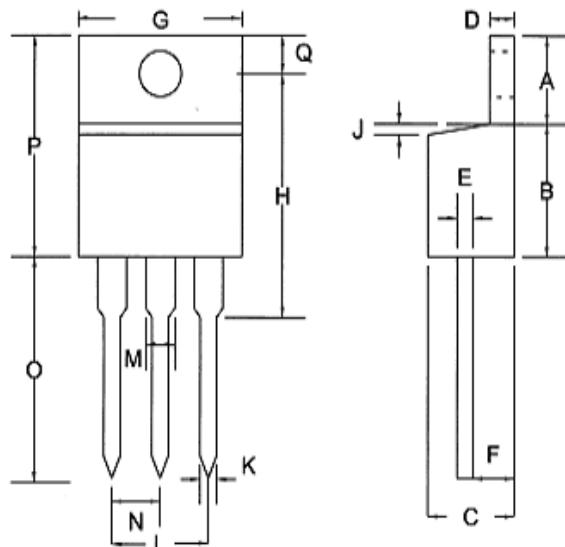
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Package Details

Package: TO220C Leaded Plastic Package



Symbol	Dimensions In Millimeters			Dimensions In Inches		
	Min	Nom	Max	Min	Nom	Max
A	5.58	6.54	7.49	0.220	0.257	0.295
B	8.38	8.64	8.90	0.330	0.340	0.350
C	4.07	4.45	4.82	0.160	0.175	0.190
D	1.15	1.27	1.39	0.045	0.050	0.055
E	0.35	0.45	0.60	0.014	0.018	0.024
F	2.04	2.42	2.79	0.080	0.095	0.110
G	9.66	9.97	10.28	0.380	0.393	0.405
H	—	16.25	—	—	0.640	—
I	3.68	3.83	3.98	0.145	0.151	0.157
J	—	—	1.27	—	—	0.050
K	0.75	0.85	0.95	0.030	0.033	0.037
L	4.83	5.08	5.33	0.190	0.200	0.210
M	1.15	1.33	1.52	0.045	0.052	0.060
N	2.42	2.54	2.66	0.095	0.100	0.105
O	12.70	13.48	14.27	0.500	0.531	0.562
P	14.48	15.17	15.87	0.570	0.597	0.625
Q	2.54	2.79	3.04	0.100	0.110	0.120

Packing	Tube (Pcs)	Inner Box (Pcs)	Per Carton (Pcs)
Tube	50	1,000	8000

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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH



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Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone +91-11-2579 6150, 4141 1112 Fax +91-11-2579 5290, 4141 1119

email@cdil.com www.cdil.com

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